NSN 5961-01-235-8889

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View Online at https://aerobasegroup.com/nsn/5961-01-235-8889

Inclosure Material:

Metal

Overall Length:

0.260 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.370 inches

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case and quality assurance level txv

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

175.0 collector to base voltage/static/emitter open and 175.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

1.00 amperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector preset

Transfer Ratio:

300.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Inuclear hardness critical items, no drawing to determine if isc code 1 item should also be nuclear hardness. Can't change criticality code to reflect nuclear hardness; junction pattern arrangement: pnp

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/357 government specification

Shelf Life:

N/a

Unit Of Measure:

Domilitorization

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